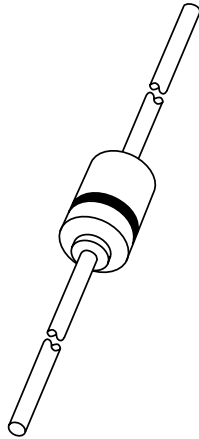


DATA SHEET



BZV85 series Voltage regulator diodes

Product specification
Supersedes data of 1996 Apr 26

1999 May 11

Voltage regulator diodes

BZV85 series

FEATURES

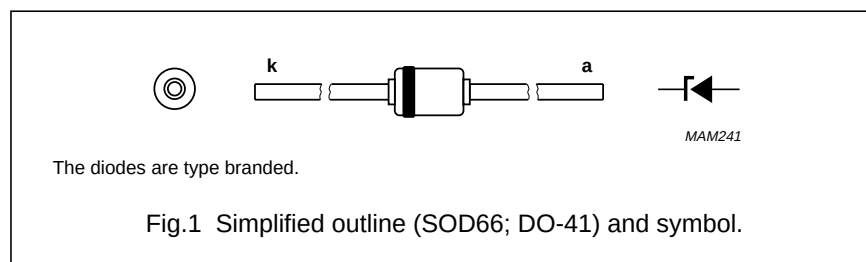
- Total power dissipation: max. 1.3 W
- Tolerance series: approx. $\pm 5\%$
- Working voltage range: nom. 3.6 to 75 V (E24 range)
- Non-repetitive peak reverse power dissipation: max. 60 W.

APPLICATIONS

- Stabilization purposes.

DESCRIPTION

Medium-power voltage regulator diodes in hermetically sealed leaded glass SOD66 (DO-41) packages. The diodes are available in the normalized E24 approx. $\pm 5\%$ tolerance range. The series consists of 33 types with nominal working voltages from 3.6 to 75 V (BZV85-C3V6 to BZV85-C75).



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I_F	continuous forward current		—	500	mA
I_{ZSM}	non-repetitive peak reverse current	$t_p = 100 \mu s$; square wave; $T_j = 25^\circ C$ prior to surge; see Fig.3	see Table "Per type"		
		$t_p = 10 ms$; half sinewave; $T_j = 25^\circ C$ prior to surge	see Table "Per type"		
P_{tot}	total power dissipation	$T_{amb} = 25^\circ C$; lead length 10 mm; note 1	—	1	W
		note 2	—	1.3	W
P_{ZSM}	non-repetitive peak reverse power dissipation	$t_p = 100 \mu s$; square wave; $T_j = 25^\circ C$ prior to surge	—	60	W
T_{stg}	storage temperature		-65	+200	$^\circ C$
T_j	junction temperature		—	200	$^\circ C$

Notes

1. Device mounted on a printed circuit-board with 1 cm² copper area per lead.
2. If the leads are kept at $T_{tp} = 55^\circ C$ at 4 mm from body.

ELECTRICAL CHARACTERISTICS

Total series

$T_j = 25^\circ C$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MAX.	UNIT
V_F	forward voltage	$I_F = 50 mA$; see Fig.4	1	V

Voltage regulator diodes

BZV85 series

Per type

$T_j = 25\text{ }^{\circ}\text{C}$ unless otherwise specified.

BZV85- CXXX	WORKING VOLTAGE V _Z (V) at I _{Ztest}		DIFFERENTIAL RESISTANCE r _{dif} (Ω) at I _{Ztest}	TEMP. COEFF. S _Z (mV/K) at I _{Ztest} see Figs 5 and 6		TEST CURRENT I _{Ztest} (mA)	DIODE CAP. C _d (pF) at f = 1 MHz; V _R = 0 V	REVERSE CURRENT at REVERSE VOLTAGE		NON-REPETITIVE PEAK REVERSE CURRENT I _{ZSM}		
	MIN.	MAX.		MAX.	MIN.			MAX.	I _R (μA)	V _R (V)	at t _p = 100 μs; T _{amb} = 25 °C	at t _p = 10 ms; T _{amb} = 25 °C
											MAX. (A)	MAX. (mA)
3V6	3.4	3.8	15	−3.5	−1.0	60	450	50	1.0	8.0	2000	
3V9	3.7	4.1	15	−3.5	−1.0	60	450	10	1.0	8.0	1950	
4V3	4.0	4.6	13	−2.7	0	50	450	5	1.0	8.0	1850	
4V7	4.4	5.0	13	−2.0	+0.7	45	300	3	1.0	8.0	1800	
5V1	4.8	5.4	10	−0.5	+2.2	45	300	3	2.0	8.0	1750	
5V6	5.2	6.0	7	0	2.7	45	300	2	2.0	8.0	1700	
6V2	5.8	6.6	4	0.6	3.6	35	200	2	3.0	7.0	1620	
6V8	6.4	7.2	3.5	1.3	4.3	35	200	2	4.0	7.0	1550	
7V5	7.0	7.9	3	2.5	5.5	35	150	1	4.5	5.0	1500	
8V2	7.7	8.7	5	3.1	6.1	25	150	0.7	5.0	5.0	1400	
9V1	8.5	9.6	5	3.8	7.2	25	150	0.7	6.5	4.0	1340	
10	9.4	10.6	8	4.7	8.5	25	90	0.2	7.0	4.0	1200	
11	10.4	11.6	10	5.3	9.3	20	85	0.2	7.7	3.0	1100	
12	11.4	12.7	10	6.3	10.8	20	85	0.2	8.4	3.0	1000	
13	12.4	14.1	10	7.4	12.0	20	80	0.2	9.1	3.0	900	
15	13.8	15.6	15	8.9	13.6	15	75	0.05	10.5	2.5	760	
16	15.3	17.1	15	10.7	15.4	15	75	0.05	11.0	1.75	700	
18	16.8	19.1	20	11.8	17.1	15	70	0.05	12.5	1.75	600	
20	18.8	21.2	24	13.6	19.1	10	60	0.05	14.0	1.75	540	
22	20.8	23.3	25	16.6	22.1	10	60	0.05	15.5	1.5	500	
24	22.8	25.6	30	18.3	24.3	10	55	0.05	17	1.5	450	
27	25.1	28.9	40	20.1	27.5	8	50	0.05	19	1.2	400	
30	28.0	32.0	45	22.4	32.0	8	50	0.05	21	1.2	380	

Voltage regulator diodes

BZV85 series

BZV85- CXXX	WORKING VOLTAGE V _Z (V) at I _{Ztest}		DIFFERENTIAL RESISTANCE r _{dif} (Ω) at I _{Ztest}	TEMP. COEFF. S _Z (mV/K) at I _{Ztest} see Figs 5 and 6		TEST CURRENT I _{Ztest} (mA)	DIODE CAP. C _d (pF) at f = 1 MHz; V _R = 0 V	REVERSE CURRENT at REVERSE VOLTAGE		NON-REPETITIVE PEAK REVERSE CURRENT I _{ZSM}	
	MIN.	MAX.	MAX.	MIN.	MAX.			I _R (μA)	V _R (V)	at t _p = 100 μs; T _{amb} = 25 °C	at t _p = 10 ms; T _{amb} = 25 °C
							MAX.	MAX.		MAX. (A)	MAX. (mA)
33	31.0	35.0	45	24.8	35.0	8	45	0.05	23	1.0	350
36	34.0	38.0	50	27.2	39.9	8	45	0.05	25	0.9	320
39	37.0	41.0	60	29.6	43.0	6	45	0.05	27	0.8	296
43	40.0	46.0	75	34.0	48.3	6	40	0.05	30	0.7	270
47	44.0	50.0	100	37.4	52.5	4	40	0.05	33	0.6	246
51	48.0	54.0	125	40.8	56.5	4	40	0.05	36	0.5	226
56	52.0	60.0	150	46.8	63.0	4	40	0.05	39	0.4	208
62	58.0	66.0	175	52.2	72.5	4	35	0.05	43	0.4	186
68	64.0	72.0	200	60.5	81.0	4	35	0.05	48	0.35	171
75	70.0	80.0	225	66.5	88.0	4	35	0.05	53	0.3	161

Voltage regulator diodes

BZV85 series

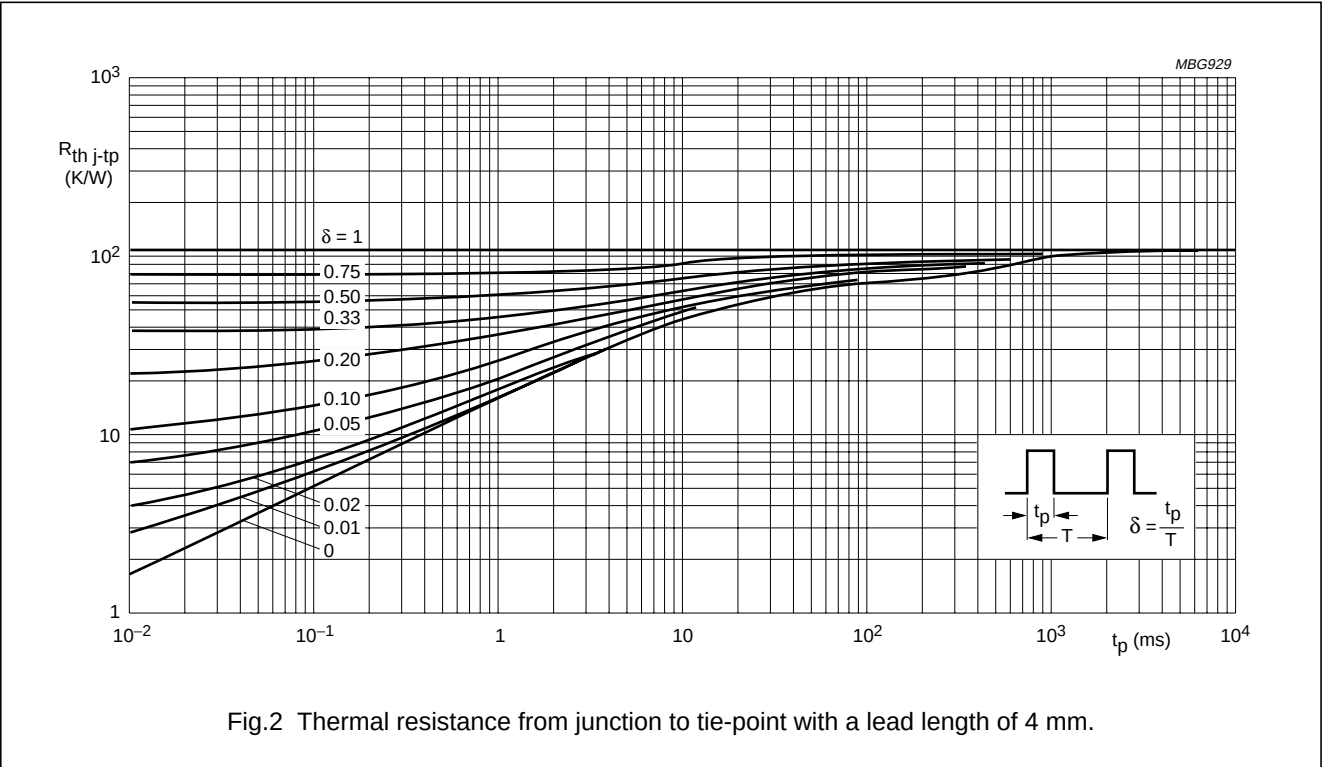
THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j-tp}$	thermal resistance from junction to tie-point	lead length 4 mm; see Fig.2	110	K/W
$R_{th\ j-a}$	thermal resistance from junction to ambient	lead length 10 mm; note 1	175	K/W

Note

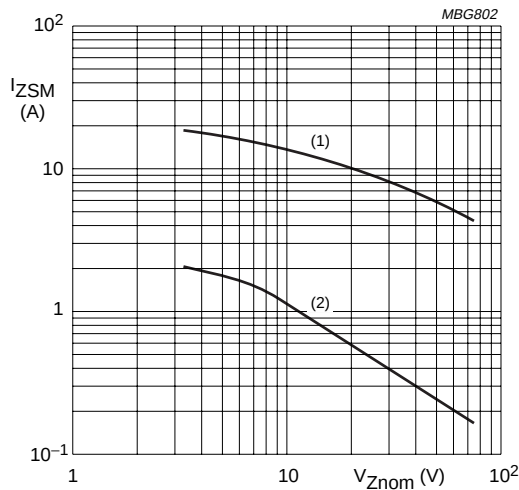
1. Device mounted on a printed circuit-board with 1 cm² copper area per lead.

GRAPHICAL DATA



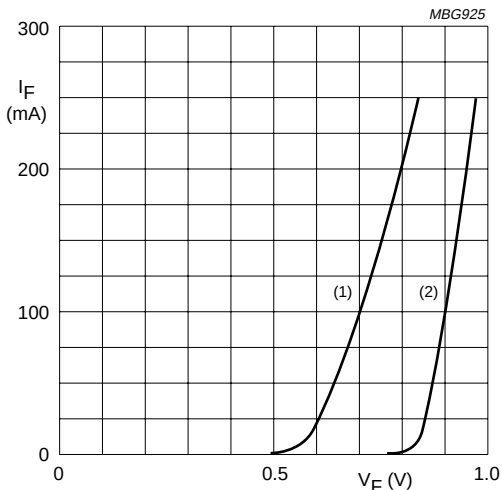
Voltage regulator diodes

BZV85 series



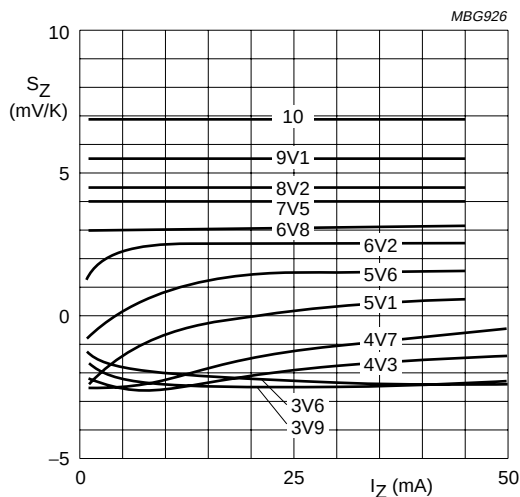
(1) $t_p = 10 \mu s$; half sinewave; $T_{amb} = 25 \text{ }^\circ C$.
(2) $t_p = 10 ms$; half sinewave; $T_{amb} = 25 \text{ }^\circ C$.

Fig.3 Non-repetitive peak reverse current as a function of the nominal working voltage.



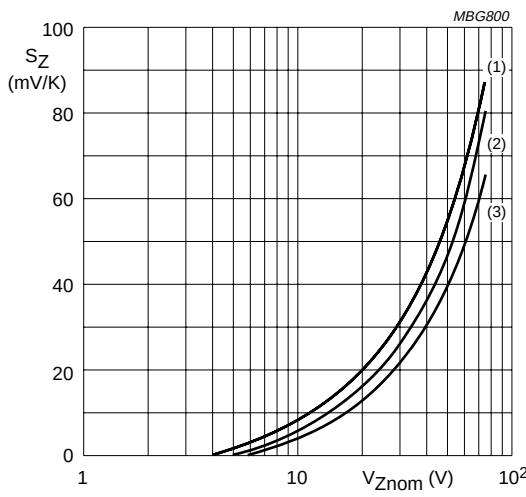
(1) $T_j = 200 \text{ }^\circ C$.
(2) $T_j = 25 \text{ }^\circ C$.

Fig.4 Forward current as a function of forward voltage; typical values.



BZV85-C3V6 to C10.
 $T_j = 25 \text{ to } 150 \text{ }^\circ C$.
For types above 7.5 V the temperature coefficient is independent of current; see Table "Per type".

Fig.5 Temperature coefficient as a function of working current; typical values.



$I_Z = I_{Ztest}$; $T_j = 25 \text{ to } 150 \text{ }^\circ C$.
(1) Maximum values.
(2) Typical values.
(3) Minimum values.

Fig.6 Temperature coefficient as a function of nominal working voltage.

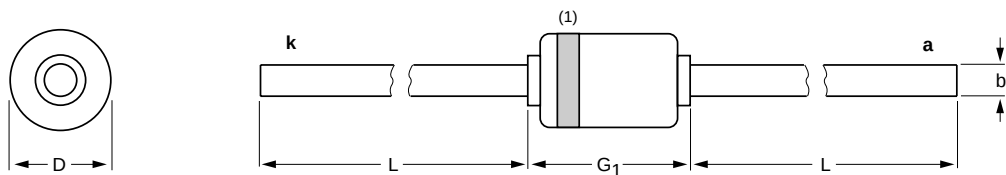
Voltage regulator diodes

BZV85 series

PACKAGE OUTLINE

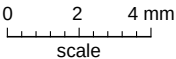
Hermetically sealed glass package; axial leaded; 2 leads

SOD66



DIMENSIONS (mm are the original dimensions)

UNIT	b max.	D max.	G ₁ max.	L min.
mm	0.81	2.6	4.8	28



Note
1. The marking band indicates the cathode.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOD66		DO-41				97-06-20

DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	

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